

# S-82P1A Series

Rev.1.0 00

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## BATTERY PROTECTION IC WITH CHARGE-DISCHARGE CONTROL FUNCTION FOR 1-CELL PACK

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The S-82P1A Series is a protection IC for lithium-ion / lithium polymer rechargeable batteries, which includes high-accuracy voltage detection circuits and delay circuits. It is suitable for protecting 1-cell lithium-ion / lithium polymer rechargeable battery packs from overcharge, overdischarge, and overcurrent.

By using an external overcurrent detection resistor, the S-82P1A Series realizes high-accuracy overcurrent protection with less effect from temperature change.

The S-82P1A Series also has an input pin for charge-discharge control signal, allowing for charge-discharge control with an external signal.

## Features

High-accuracy voltage detection circuit		
Overcharge detection voltage	3.500 V to 4.800 V (5 mV step)	Accuracy ±15 mV
Overcharge release voltage	3.100 V to 4.800 V*1	Accuracy ±50 mV
Overdischarge detection voltage	2.000 V to 3.000 V (10 mV step)	Accuracy $\pm 50 \text{ mV}$
Overdischarge release voltage	2.000 V to 3.400 V*2	Accuracy $\pm$ 75 mV
Discharge overcurrent detection voltage 1	3 mV to 100 mV (0.25 mV step)	Accuracy $\pm 0.75$ mV
Discharge overcurrent detection voltage 2	6 mV to 100 mV (0.5 mV step)	Accuracy ±2 mV
Load short-circuiting detection voltage	20 mV to 100 mV (1 mV step)	Accuracy ±5 mV
Charge overcurrent detection voltage	–100 mV to –3 mV (0.25 mV step)	Accuracy ±0.75 mV
<ul> <li>Detection delay times are generated only by an interview.</li> </ul>	ernal circuit (external capacitors are	unnecessary).
<ul> <li>Charge-discharge control function</li> </ul>		
CTL pin control logic:	Active "H", active "L"	
CTL pin internal resistance connection:	Pull-up, pull-down	
CTL pin internal resistance value:	1 M $\Omega$ to 6 M $\Omega$ (1 M $\Omega$ step)	
<ul> <li>Discharge overcurrent control function</li> </ul>		
Release condition of discharge overcurrent status:	Load disconnection	
Release voltage of discharge overcurrent status:	Discharge overcurrent release vol	tage ( $V_{RIOV}$ ) = $V_{DD} \times 0.8$ (typ.)
Discharge overcurrent status reset function by CTL pi	n: Available, unavailable	
0 V battery charge:	Enabled, inhibited	
Power-down function:	Available, unavailable	
<ul> <li>High-withstand voltage:</li> </ul>	VM pin and CO pin: Absolute	e maximum rating 28 V
Wide operation temperature range:	Ta = -40°C to +85°C	5
Low current consumption		
During operation:	2.0 μA typ., 4.0 μA max. (Ta = +2	5°C)
During power-down:	50 nA max. (Ta = +25°C)	,
During overdischarge:	0.5 μA max. (Ta = +25°C)	
<ul> <li>Lead-free (Sn 100%), halogen-free</li> </ul>		
*1. Overcharge release voltage = Overcharge detec		-

(Overcharge hysteresis voltage can be selected as 0 V or from a range of 0.1 V to 0.4 V in 50 mV step.)
\*2. Overdischarge release voltage = Overdischarge detection voltage + Overdischarge hysteresis voltage (Overdischarge hysteresis voltage can be selected as 0 V or from a range of 0.1 V to 0.7 V in 100 mV step.)

## Applications

- · Lithium-ion rechargeable battery pack
- Lithium polymer rechargeable battery pack

# Package

• HSNT-8(1616)

## BATTERY PROTECTION IC WITH CHARGE-DISCHARGE CONTROL FUNCTION FOR 1-CELL PACK S-82P1A Series Rev.1.0\_00

## Block Diagram

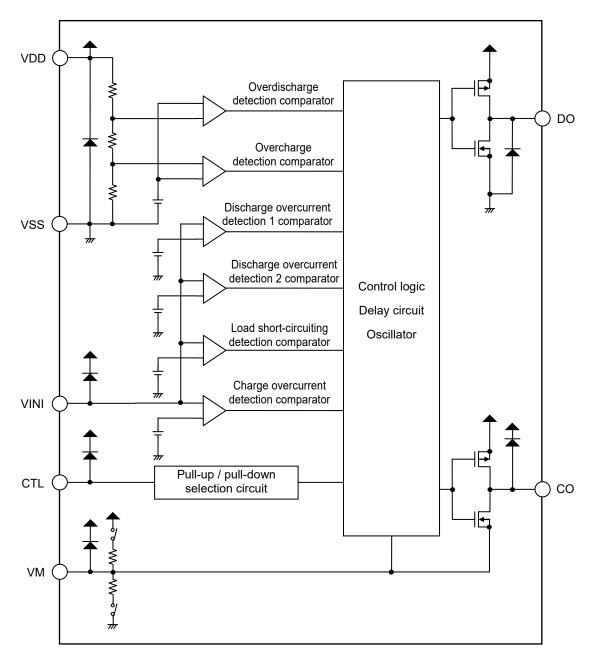
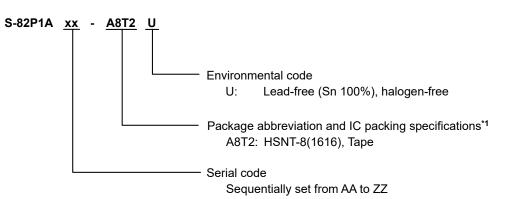


Figure 1

## Product Name Structure

1. Product name



### \*1. Refer to the tape drawing.

## 2. Package

Table 1 Package Drawing Codes										
Package Name	Dimension	Таре	Reel	Land						
HSNT-8(1616)	PY008-A-P-SD	PY008-A-C-SD	PY008-A-R-SD	PY008-A-L-SD						

### 3. Product name list

	Table 2 (1 / 2)											
	Overcharge	Overcharge	Overdischarge	Overdischarge Overdischarge								
Product Name	Detection	Release	Detection	Release	Delay Time	CTL Pin	Function					
Product Name	Voltage	Voltage	Voltage	Voltage	Combination*1	Combination*2	Combination*3					
	[V <sub>CU</sub> ]	[V <sub>CL</sub> ]	[V <sub>DL</sub> ]	[V <sub>DU</sub> ]								
S-82P1AAA-A8T2U	4.520 V	4.370 V	2.350 V	2.550 V	(1)	(1)	(1)					

## Table 2 (2 / 2)

Product Name	Discharge Overcurrent	Discharge Overcurrent	Load Short-circuiting	Charge Overcurrent
	Detection Voltage 1	Detection Voltage 2	Detection Voltage	Detection Voltage
	[VDIOV1]	[VDIOV2]	[Vsнокт]	[Vciov]
S-82P1AAA-A8T2U	7 mV	14 mV	28 mV	–14 mV

\*1. Refer to Table 3 about the details of the delay time combinations.

\*2. Refer to Table 5 about the details of the CTL pin combinations.

**\*3.** Refer to **Table 6** about the details of the function combinations.

Remark Please contact our sales representatives for products other than the above.

## BATTERY PROTECTION IC WITH CHARGE-DISCHARGE CONTROL FUNCTION FOR 1-CELL PACK S-82P1A Series Rev.1.0\_00

	Table 3												
Delay Time Combination	Overcharge Detection Delay Time [tcu]	Overdischarge Detection Delay Time [t <sub>DL</sub> ]	Discharge Overcurrent Detection Delay Time 1 [t <sub>DIOV1</sub> ]	Discharge Overcurrent Detection Delay Time 2 [t <sub>DIOV2</sub> ]	Load Short- circuiting Detection Delay Time [t <sub>SHORT</sub> ]	Charge Overcurrent Detection Delay Time [t <sub>CIOV</sub> ]	Charge- discharge Inhibition Delay Time [tctl]						
(1)	1.0 s	64 ms	3.75 s	16 ms	280 μs	16 ms	48 ms						

**Remark** The delay times can be changed within the range listed below. For details, please contact our sales representatives.

Table 4											
Delay Time	Symbol			Selection	n Range			Remark			
Overcharge detection delay time	tcu	256 ms	512 ms	1.0 s	_	_	_	Select a value from the left.			
Overdischarge detection delay time	t <sub>DL</sub>	32 ms	64 ms	128 ms	_	_	_	Select a value from the left.			
Diaskana ana ang ang ang ang ang ang ang ang		8 ms	16 ms	32 ms	64 ms	128 ms	256 ms				
Discharge overcurrent detection delay time 1	t <sub>DIOV1</sub>	512 ms	1.0 s	1.28 s	2.0 s	3.0 s	3.75 s	Select a value from the left.			
detection delay time 1		4.0 s	-	-	-	-	-	nom me lon.			
Discharge overcurrent detection delay time 2	t <sub>DIOV2</sub>	4 ms	8 ms	16 ms	32 ms	64 ms	128 ms	Select a value from the left.			
Load short-circuiting detection delay time	<b>t</b> SHORT	280 μs	530 μs	-	-	-	-	Select a value from the left.			
Charge overcurrent detection delay time	tciov	4 ms	8 ms	16 ms	32 ms	64 ms	128 ms	Select a value from the left.			
Charge-discharge inhibition delay time	t <sub>CTL</sub>	2 ms	4 ms	48 ms	64 ms	128 ms	256 ms	Select a value from the left.			

## Table 5

CTL Pin Combination	Control Logic*1	Internal Resistance Connection *2	Internal Resistance Value <sup>*3</sup> [RcтL]	CTL Pin Voltage "H"* <sup>4</sup> [Vстьн]	CTL Pin Voltage "L" <sup>*5</sup> [Vcτ∟L]
(1)	Active "H"	Pull-down	5 MΩ	$V_{SS} + 0.65 V$	$V_{SS} + 0.60 V$

\*1. CTL pin control logic: Active "H", active "L"

**\*2.** CTL pin internal resistance connection: Pull-up, pull-down

\*3. CTL pin internal resistance value: 1 M $\Omega$  to 6 M $\Omega$  (1 M $\Omega$  step)

\*4. CTL pin voltage "H":  $V_{\text{SS}}$  + 0.65 V,  $V_{\text{DD}}$  – 0.9 V

**\*5.** CTL pin voltage "L": V<sub>SS</sub> + 0.60 V, V<sub>DD</sub> - 0.9 V

Remark Please contact our sales representatives for products with CTL pin combinations other than the above.

### Table 6

Function Combination	0 V Battery Charge*1	Power-down Function*2
(1)	Enabled	Unavailable

\*1. 0 V battery charge: Enabled, inhibited

\*2. Power-down function: Available, unavailable

Remark Please contact our sales representatives for products with function combinations other than the above.

# ABLIC Inc.

## Pin Configuration

## 1. HSNT-8(1616)

Top view	Table 7							
1 [0] 8	Pin No.	Symbol	Description					
4 5	1	CTL	Input pin for charge-discharge control signal					
	2	VM	Input pin for external negative voltage					
Bottom view	3	со	Connection pin of charge control FET gate (CMOS output)					
	4	DO	Connection pin of discharge control FET gate (CMOS output)					
	5	VSS	Input pin for negative power supply					
*1	6	VDD	Input pin for positive power supply					
	7	VINI	Overcurrent detection pin					
Figure 2	8	NC*2	No connection					

\*1. Connect the heat sink of backside at shadowed area to the board, and set electric potential open or  $V_{DD}$ . However, do not use it as the function of electrode.

\*2. The NC pin is electrically open. The NC pin can be connected to VDD pin or VSS pin.

## Absolute Maximum Ratings

Table 8

	(Ta = +25°C unless otherwise	e specified)		
Item	Symbol	Applied Pin	Absolute Maximum Rating	Unit
Input voltage between VDD pin and VSS pin	V <sub>DS</sub>	VDD	$V_{\text{SS}} - 0.3$ to $V_{\text{SS}} + 6$	V
VINI pin input voltage	V <sub>VINI</sub>	VINI	$V_{DD} - 6$ to $V_{DD} + 0.3$	V
CTL pin input voltage	VCTL	CTL	$V_{DD} - 6$ to $V_{DD} + 0.3$	V
VM pin input voltage	Vvm	VM	$V_{DD} - 28$ to $V_{DD} + 0.3$	V
DO pin output voltage	V <sub>DO</sub>	DO	$V_{\text{SS}} - 0.3$ to $V_{\text{DD}} + 0.3$	V
CO pin output voltage	Vco	со	$V_{DD} - 28$ to $V_{DD} + 0.3$	V
Operation ambient temperature	Topr	_	-40 to +85	°C
Storage temperature	T <sub>stg</sub>	_	–55 to +125	°C

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

## Thermal Resistance Value

Table 9												
Item	Symbol	Conc	Min.	Тур.	Max.	Unit						
			Board A	_	214	_	°C/W					
			Board B	-	172	_	°C/W					
Junction-to-ambient thermal resistance*1	θја	HSNT-8(1616)	Board C	I	-	_	°C/W					
			Board D	I	-	_	°C/W					
			Board E	_	_	_	°C/W					

- . . .

\*1. Test environment: compliance with JEDEC STANDARD JESD51-2A

**Remark** Refer to "**■ Power Dissipation**" and "**Test Board**" for details.

## Electrical Characteristics

1. Ta = +25°C

		Table 10	(	(Ta = +25°C	unless otherw	ise sp	ecified)
ltem	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Detection Voltage						•	
Overcharge detection voltage	V <sub>CU</sub>	-	$V_{\text{CU}}-0.015$	V <sub>CU</sub>	$V_{CU} + 0.015$	V	1
Overcharge release voltage	V <sub>CL</sub>	V <sub>CL</sub> ≠ V <sub>CU</sub>	$V_{\text{CL}}-0.050$	V <sub>CL</sub>	$V_{CL} + 0.050$	V	1
	V CL	$V_{CL} = V_{CU}$	$V_{\text{CL}}-0.020$	V <sub>CL</sub>	$V_{CL} + 0.015$	V	1
Overdischarge detection voltage	V <sub>DL</sub>	-	$V_{\text{DL}}-0.050$	V <sub>DL</sub>	$V_{DL} + 0.050$	V	2
Overdiesberge release veltage	V	V <sub>DL</sub> ≠ V <sub>DU</sub>	$V_{\text{DU}}-0.075$	V <sub>DU</sub>	$V_{\text{DU}} + 0.075$	V	2
Overdischarge release voltage	V <sub>DU</sub>	$V_{DL} = V_{DU}$	$V_{\text{DU}}-0.050$	V <sub>DU</sub>	$V_{DU} + 0.050$	V	2
Discharge overcurrent detection voltage 1	V <sub>DIOV1</sub>	-	$V_{\text{DIOV1}}-0.75$	V <sub>DIOV1</sub>	$V_{\text{DIOV1}} + 0.75$	mV	5
Discharge overcurrent detection voltage 2	V <sub>DIOV2</sub>	-	$V_{\text{DIOV2}}-2$	V <sub>DIOV2</sub>	$V_{DIOV2} + 2$	mV	2
Load short-circuiting detection voltage	V <sub>SHORT</sub>	-	V <sub>SHORT</sub> – 5	VSHORT	V <sub>SHORT</sub> + 5	mV	2
Load short-circuiting detection voltage 2	V <sub>SHORT2</sub>	-	V <sub>DD</sub> – 1.2	V <sub>DD</sub> - 0.8	$V_{DD}-0.5$	V	2
Charge overcurrent detection voltage	V <sub>CIOV</sub>	-	$V_{\text{CIOV}} - 0.75$	V <sub>CIOV</sub>	V <sub>CIOV</sub> + 0.75	mV	2
Discharge overcurrent release voltage	V <sub>RIOV</sub>	V <sub>DD</sub> = 3.4 V	$V_{DD}  imes 0.77$	$V_{DD}  imes 0.80$	$V_{\text{DD}}  imes 0.83$	V	5
0 V Battery Charge	•					•	
0 V battery charge starting charger voltage	V <sub>0CHA</sub>	0 V battery charge enabled	0.7	1.1	1.5	V	4
0 V battery charge inhibition battery voltage	V <sub>0INH</sub>	0 V battery charge inhibited	0.9	1.2	1.5	V	2
Internal Resistance						_	
Resistance between VDD pin and VM pin	R <sub>VMD</sub>	V <sub>DD</sub> = 1.8 V, V <sub>VM</sub> = 0 V	500	1250	2500	kΩ	3
Resistance between VM pin and VSS pin	R <sub>VMS</sub>	V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 1.0 V	5	10	15	kΩ	3
CTL pin internal resistance	R <sub>CTL</sub>	-	$R_{\text{CTL}} \times 0.5$	R <sub>CTL</sub>	$R_{\text{CTL}}  imes 2.0$	$M\Omega$	3
Input Voltage	1	1					
Operation voltage between VDD pin and VSS pin	V <sub>DSOP1</sub>	-	1.5	-	6.0	V	-
Operation voltage between VDD pin and VM pin	V <sub>DSOP2</sub>	-	1.5	-	28	V	-
CTL pin voltage "H"	V <sub>CTLH</sub>	V <sub>DD</sub> = 3.4 V	$V_{\text{CTLH}} - 0.3$	V <sub>CTLH</sub>	$V_{\text{CTLH}} + 0.3$	V	2
CTL pin voltage "L"	V <sub>CTLL</sub>	-	$V_{\text{CTLL}}-0.3$	VCTLL	$V_{\text{CTLL}} + 0.3$	V	2
Input Current							
Current consumption during operation	I <sub>OPE</sub>	$V_{DD}$ = 3.4 V, $V_{VM}$ = 0 V	_	2.0	4.0	μΑ	3
Current consumption during power-down	I <sub>PDN</sub>	V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V	-	_	0.05	μΑ	3
Current consumption during overdischarge	IOPED	$V_{DD} = V_{VM} = 1.5 V$	_	-	0.5	μA	3
Output Resistance	1	II		1		1	
CO pin resistance "H"	RCOH	-	5	10	20	kΩ	4
CO pin resistance "L"	R <sub>COL</sub>	-	1.5	3	6	kΩ	4
DO pin resistance "H"	RDOH	-	5	10	20	kΩ	4
DO pin resistance "L"	R <sub>DOL</sub>	-	1	2	4	kΩ	4
Delay Time	1	1		1		1	
Overcharge detection delay time	t <sub>CU</sub>	-	$t_{CU} \times 0.7$	t <sub>CU</sub>	$t_{CU} \times 1.3$	-	5
Overdischarge detection delay time	t <sub>DL</sub>	-	$t_{DL} \times 0.7$	t <sub>DL</sub>	$t_{DL} \times 1.3$	-	5
Discharge overcurrent detection delay time 1	t <sub>DIOV1</sub>	-	$t_{\text{DIOV1}}  imes 0.75$	t <sub>DIOV1</sub>	$t_{\text{DIOV1}} \times 1.25$	-	5
Discharge overcurrent detection delay time 2	t <sub>DIOV2</sub>	-	$t_{\text{DIOV2}} \times 0.7$	t <sub>DIOV2</sub>	$t_{DIOV2} \times 1.3$	-	5
Load short-circuiting detection delay time	t <sub>SHORT</sub>	-	t <sub>SHORT</sub> × 0.7	t <sub>SHORT</sub>	t <sub>SHORT</sub> × 1.3	-	5
Charge overcurrent detection delay time	t <sub>CIOV</sub>	-	$t_{CIOV} \times 0.7$	tciov	$t_{CIOV} \times 1.3$	-	5
Charge-discharge inhibition delay time	t <sub>CTL</sub>	-	$t_{CTL} \times 0.7$	t <sub>CTL</sub>	$t_{CTL} \times 1.3$	-	5

# BATTERY PROTECTION IC WITH CHARGE-DISCHARGE CONTROL FUNCTION FOR 1-CELL PACK S-82P1A Series Rev.1.0\_00

## 2. Ta = $-20^{\circ}$ C to $+60^{\circ}$ C<sup>\*1</sup>

		Table 11	(Ta = –20°0	C to +60°C*1	unless otherw	ise sp	ecified)
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Detection Voltage							
Overcharge detection voltage	V <sub>CU</sub>	-	$V_{\text{CU}}-0.020$	V <sub>CU</sub>	$V_{CU} + 0.020$	V	1
Overcharge release voltage	V <sub>CL</sub>	$V_{CL} \neq V_{CU}$ $V_{CL} = V_{CU}$	$V_{CL} - 0.065$ $V_{CL} - 0.025$	V <sub>CL</sub>	$V_{CL}$ + 0.057 $V_{CL}$ + 0.020	V V	1
Overdischarge detection voltage	V <sub>DL</sub>		$V_{CL} = 0.023$ $V_{DL} = 0.060$	VCL	V <sub>CL</sub> +0.020 V <sub>DL</sub> +0.055	V	2
	V DL					V	
Overdischarge release voltage	V <sub>DU</sub>	V <sub>DL</sub> ≠ V <sub>DU</sub> V <sub>DL</sub> = V <sub>DU</sub>	V <sub>DU</sub> - 0.085 V <sub>DU</sub> - 0.060	V <sub>DU</sub> V <sub>DU</sub>	V <sub>DU</sub> +0.080 V <sub>DU</sub> +0.055	V	2
Discharge overcurrent detection voltage 1	V <sub>DIOV1</sub>	-	V <sub>DIOV1</sub> - 1.25	V <sub>DIOV1</sub>	V <sub>DIOV1</sub> + 1.25	mV	5
Discharge overcurrent detection voltage 2	V <sub>DIOV2</sub>	_	V <sub>DIOV2</sub> – 2.5	V <sub>DIOV2</sub>	V <sub>DIOV2</sub> + 2.5	mV	2
Load short-circuiting detection voltage	VSHORT	_	V <sub>SHORT</sub> – 5	VSHORT	V <sub>SHORT</sub> + 5	mV	2
Load short-circuiting detection voltage 2	V <sub>SHORT2</sub>	_	V <sub>DD</sub> – 1.4	V <sub>DD</sub> - 0.8	V <sub>DD</sub> – 0.3	V	2
	1	_					
Charge overcurrent detection voltage	Vciov	-	V <sub>CIOV</sub> – 1.25		$V_{CIOV} + 1.25$	mV V	2
Discharge overcurrent release voltage 0 V Battery Charge	VRIOV	V <sub>DD</sub> = 3.4 V	$V_{DD} \times 0.77$	$V_{DD}  imes 0.80$	$V_{DD}  imes 0.83$	V	5
0 V battery charge starting charger voltage	V <sub>0CHA</sub>	0 V battery charge enabled	0.5	1.1	1.7	V	4
0 V battery charge inhibition battery voltage	VOINH	0 V battery charge inhibited	0.7	1.2	1.7	V	2
Internal Resistance				•			
Resistance between VDD pin and VM pin	R <sub>VMD</sub>	V <sub>DD</sub> = 1.8 V, V <sub>VM</sub> = 0 V	250	1250	3500	kΩ	3
Resistance between VM pin and VSS pin	R <sub>VMS</sub>	V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 1.0 V	3.5	10	20	kΩ	3
CTL pin internal resistance	R <sub>CTL</sub>	-	$R_{CTL}  imes 0.25$	R <sub>CTL</sub>	$R_{CTL}  imes 3.0$	MΩ	3
Input Voltage							
Operation voltage between VDD pin and VSS pin	V <sub>DSOP1</sub>	-	1.5	_	6.0	V	-
Operation voltage between VDD pin and VM pin	V <sub>DSOP2</sub>	-	1.5	-	28	V	-
CTL pin voltage "H"	V <sub>CTLH</sub>	V <sub>DD</sub> = 3.4 V	$V_{\text{CTLH}} - 0.4$	V <sub>CTLH</sub>	$V_{\text{CTLH}} + 0.4$	V	2
CTL pin voltage "L"	V <sub>CTLL</sub>	-	$V_{\text{CTLL}} - 0.4$	V <sub>CTLL</sub>	$V_{CTLL} + 0.4$	V	2
Input Current							
Current consumption during operation	I <sub>OPE</sub>	V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 0 V	-	2.0	5.0	μA	3
Current consumption during power-down	I <sub>PDN</sub>	V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V	-	-	0.1	μA	3
Current consumption during overdischarge	I <sub>OPED</sub>	V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V	-	-	1.0	μA	3
Output Resistance							
CO pin resistance "H"	RCOH	-	2.5	10	30	kΩ	4
CO pin resistance "L"	R <sub>COL</sub>	-	0.75	3	9	kΩ	4
DO pin resistance "H"	R <sub>DOH</sub>	-	2.5	10	30	kΩ	4
DO pin resistance "L"	R <sub>DOL</sub>	-	0.5	2	6	kΩ	4
Delay Time							
Overcharge detection delay time	t <sub>CU</sub>	-	$t_{CU}  imes 0.6$	tc∪	$t_{CU}  imes 1.4$	-	5
Overdischarge detection delay time	t <sub>DL</sub>	-	$t_{DL} \times 0.6$	t <sub>DL</sub>	$t_{DL} \times 1.4$	-	5
Discharge overcurrent detection delay time 1	t <sub>DIOV1</sub>	-	$t_{DIOV1} \times 0.65$	t <sub>DIOV1</sub>	t <sub>DIOV1</sub> × 1.35	_	5
Discharge overcurrent detection delay time 2	t <sub>DIOV2</sub>	_	$t_{DIOV2} \times 0.6$	t <sub>DIOV2</sub>	$t_{DIOV2} \times 1.4$	_	5
Load short-circuiting detection delay time	t <sub>SHORT</sub>	_	t <sub>SHORT</sub> × 0.6	t <sub>SHORT</sub>	$t_{SHORT} \times 1.4$	_	5
Charge overcurrent detection delay time	t <sub>CIOV</sub>	-	$t_{CIOV} \times 0.6$	t <sub>CIOV</sub>	$t_{CIOV} \times 1.4$	_	5
Charge-discharge inhibition delay time	t <sub>CTL</sub>	_	t <sub>CTL</sub> × 0.6	t <sub>CTL</sub>	$t_{CTL} \times 1.4$	_	5
			-012 / 010	-012	-012 ****	1	-

\*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

# BATTERY PROTECTION IC WITH CHARGE-DISCHARGE CONTROL FUNCTION FOR 1-CELL PACK Rev.1.0\_00 S-82P1A Series

## 3. Ta = $-40^{\circ}$ C to $+85^{\circ}$ C<sup>\*1</sup>

		Table 12	(Ta = –40°(	C to +85°C*1	unless otherw	ise sp	ecified)
Item Symbol Condition		Condition	Min.	Тур.	Max.	Unit	Test Circuit
Detection Voltage						•	
Overcharge detection voltage	V <sub>CU</sub>	-	$V_{CU} - 0.045$	V <sub>CU</sub>	V <sub>CU</sub> +0.030	V	1
		V <sub>CL</sub> ≠ V <sub>CU</sub>	$V_{CL} - 0.080$	V <sub>CL</sub>	V <sub>CL</sub> +0.060	V	1
Overcharge release voltage	V <sub>CL</sub>	V <sub>CL</sub> = V <sub>CU</sub>	V <sub>CL</sub> - 0.050	V <sub>CL</sub>	$V_{CL} + 0.030$	V	1
Overdischarge detection voltage	V <sub>DL</sub>	_	$V_{\text{DL}}-0.080$	V <sub>DL</sub>	$V_{DL} + 0.060$	V	2
		V <sub>DL</sub> ≠ V <sub>DU</sub>	V <sub>DU</sub> - 0.105	V <sub>DU</sub>	V <sub>DU</sub> +0.085	V	2
Overdischarge release voltage	V <sub>DU</sub>	V <sub>DL</sub> = V <sub>DU</sub>	V <sub>DU</sub> - 0.080	V <sub>DU</sub>	V <sub>DU</sub> +0.060	V	2
Discharge overcurrent detection voltage 1	V <sub>DIOV1</sub>	-	V <sub>DIOV1</sub> – 1.25	V <sub>DIOV1</sub>	V <sub>DIOV1</sub> + 1.25	mV	5
Discharge overcurrent detection voltage 2	V <sub>DIOV2</sub>	_	V <sub>DIOV2</sub> – 2.5	V <sub>DIOV2</sub>	$V_{DIOV2} + 2.5$	mV	2
Load short-circuiting detection voltage	VSHORT	_	V <sub>SHORT</sub> – 5	VSHORT	V <sub>SHORT</sub> + 5	mV	2
Load short-circuiting detection voltage 2	V <sub>SHORT2</sub>	_	V <sub>DD</sub> – 1.4	V <sub>DD</sub> – 0.8	V <sub>DD</sub> – 0.3	V	2
Charge overcurrent detection voltage	VCIOV	_	V <sub>CIOV</sub> – 1.25	V <sub>CIOV</sub>	V <sub>CIOV</sub> + 1.25	mV	2
Discharge overcurrent release voltage	VRIOV	V <sub>DD</sub> = 3.4 V	V <sub>DD</sub> × 0.77	$V_{DD} \times 0.80$	V <sub>DD</sub> × 0.83	V	5
0 V Battery Charge	·NOV						
0 V battery charge starting charger voltage	V <sub>0CHA</sub>	0 V battery charge enabled	0.5	1.1	1.7	V	4
0 V battery charge inhibition battery voltage	V <sub>0INH</sub>	0 V battery charge inhibited	0.7	1.2	1.7	V	2
Internal Resistance	_						
Resistance between VDD pin and VM pin	R <sub>VMD</sub>	V <sub>DD</sub> = 1.8 V, V <sub>VM</sub> = 0 V	250	1250	3500	kΩ	3
Resistance between VM pin and VSS pin	R <sub>VMS</sub>	V <sub>DD</sub> = 3.4 V, V <sub>VM</sub> = 1.0 V	3.5	10	20	kΩ	3
CTL pin internal resistance	R <sub>CTL</sub>	-	$R_{\text{CTL}} \times 0.25$	R <sub>CTL</sub>	$R_{\text{CTL}} \times 3.0$	MΩ	3
Input Voltage	1						
Operation voltage between VDD pin and VSS pin	V <sub>DSOP1</sub>	-	1.5	_	6.0	V	-
Operation voltage between VDD pin and VM pin	V <sub>DSOP2</sub>	-	1.5	-	28	V	-
CTL pin voltage "H"	V <sub>CTLH</sub>	V <sub>DD</sub> = 3.4 V	$V_{\text{CTLH}} - 0.4$	V <sub>CTLH</sub>	$V_{\text{CTLH}} + 0.4$	V	2
CTL pin voltage "L"	V <sub>CTLL</sub>	-	$V_{\text{CTLL}}-0.4$	V <sub>CTLL</sub>	$V_{\text{CTLL}} + 0.4$	V	2
Input Current	1	•					
Current consumption during operation	I <sub>OPE</sub>	$V_{DD}$ = 3.4 V, $V_{VM}$ = 0 V	_	2.0	5.0	μA	3
Current consumption during power-down	I <sub>PDN</sub>	$V_{DD} = V_{VM} = 1.5 V$	-	-	0.1	μA	3
Current consumption during overdischarge	I <sub>OPED</sub>	$V_{DD} = V_{VM} = 1.5 V$	-	-	1.0	μΑ	3
Output Resistance		i		·i		<del>.</del>	
CO pin resistance "H"	R <sub>COH</sub>	-	2.5	10	30	kΩ	4
CO pin resistance "L"	R <sub>COL</sub>	-	0.75	3	9	kΩ	4
DO pin resistance "H"	RDOH	-	2.5	10	30	kΩ	4
DO pin resistance "L"	R <sub>DOL</sub>	-	0.5	2	6	kΩ	4
Delay Time	1	1 1		, i		1	r
Overcharge detection delay time	t <sub>CU</sub>	-	$t_{CU} \times 0.4$	t <sub>CU</sub>	$t_{CU} \times 1.6$	-	5
Overdischarge detection delay time	t <sub>DL</sub>	-	$t_{DL} \times 0.4$	t <sub>DL</sub>	t <sub>DL</sub> × 1.6	-	5
Discharge overcurrent detection delay time 1	t <sub>DIOV1</sub>	-	$t_{\text{DIOV1}} \times 0.4$	t <sub>DIOV1</sub>	$t_{DIOV1} \times 1.6$	-	5
Discharge overcurrent detection delay time 2	t <sub>DIOV2</sub>	-	$t_{DIOV2} \times 0.4$	t <sub>DIOV2</sub>	$t_{DIOV2} \times 1.6$	-	5
Load short-circuiting detection delay time	t <sub>SHORT</sub>	-	$t_{SHORT} \times 0.4$	t <sub>SHORT</sub>	t <sub>SHORT</sub> × 1.6	-	5
Charge overcurrent detection delay time	t <sub>CIOV</sub>	-	$t_{CIOV} \times 0.4$	t <sub>ciov</sub>	$t_{CIOV} \times 1.6$	-	5
Charge-discharge inhibition delay time	t <sub>CTL</sub>	-	$t_{CTL}  imes 0.4$	t <sub>CTL</sub>	$t_{CTL} \times 1.6$	-	5

\*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

## Test Circuits

When CTL pin control logic is active "H", SW1 and SW3 are turned off, SW2 and SW4 are turned on. When CTL pin control logic is active "L", SW1 and SW3 are turned on, SW2 and SW4 are turned off.

# Caution Unless otherwise specified, the output voltage levels "H" and "L" at CO pin (V<sub>CO</sub>) and DO pin (V<sub>DO</sub>) are judged by the threshold voltage (1.0 V) of the N-channel FET. Judge the CO pin level with respect to V<sub>VM</sub> and the DO pin level with respect to V<sub>SS</sub>.

# 1. Overcharge detection voltage, overcharge release voltage (Test circuit 1)

Overcharge detection voltage (V<sub>CU</sub>) is defined as the voltage V1 at which V<sub>CO</sub> goes from "H" to "L" when the voltage V1 is gradually increased after setting V1 = 3.4 V. Overcharge release voltage (V<sub>CL</sub>) is defined as the voltage V1 at which V<sub>CO</sub> goes from "L" to "H" when the voltage V1 is then gradually decreased. Overcharge hysteresis voltage (V<sub>HC</sub>) is defined as the difference between V<sub>CL</sub> and V<sub>CL</sub>.

# 2. Overdischarge detection voltage, overdischarge release voltage (Test circuit 2)

Overdischarge detection voltage (V<sub>DL</sub>) is defined as the voltage V1 at which V<sub>DO</sub> goes from "H" to "L" when the voltage V1 is gradually decreased after setting V1 = 3.4 V, V2 = V5 = V6 = 0 V. Overdischarge release voltage (V<sub>DU</sub>) is defined as the voltage V1 at which V<sub>DO</sub> goes from "L" to "H" when setting V2 = 0.01 V, V5 = V6 = 0 V and when the voltage V1 is then gradually increased. Overdischarge hysteresis voltage (V<sub>HD</sub>) is defined as the difference between V<sub>DU</sub> and V<sub>DL</sub>.

# 3. Discharge overcurrent detection voltage 1, discharge overcurrent release voltage (Test circuit 5)

Discharge overcurrent detection voltage 1 ( $V_{DIOV1}$ ) is defined as the voltage V5 whose delay time for changing  $V_{DO}$  from "H" to "L" is discharge overcurrent detection delay time 1 ( $t_{DIOV1}$ ) when the voltage V5 is increased after setting V1 = 3.4 V, V2 = 1.4 V, V5 = V6 = 0 V. Discharge overcurrent release voltage ( $V_{RIOV}$ ) is defined as the voltage V2 at which  $V_{DO}$  goes from "L" to "H" when setting V2 = 3.4 V, V5 = 0 V and when the voltage V2 is then gradually decreased.

When the voltage V2 falls below  $V_{RIOV}$ ,  $V_{DO}$  will go to "H" after 1.0 ms typ. and maintain "H" during load short-circuiting detection delay time (t<sub>SHORT</sub>).

# 4. Discharge overcurrent detection voltage 2 (Test circuit 2)

Discharge overcurrent detection voltage 2 ( $V_{DIOV2}$ ) is defined as the voltage V5 whose delay time for changing  $V_{DO}$  from "H" to "L" is discharge overcurrent detection delay time 2 ( $t_{DIOV2}$ ) when the voltage V5 is increased after setting V1 = 3.4 V, V2 = 1.4 V, V5 = V6 = 0 V.

# 5. Load short-circuiting detection voltage (Test circuit 2)

Load short-circuiting detection voltage ( $V_{SHORT}$ ) is defined as the voltage V5 whose delay time for changing  $V_{DO}$  from "H" to "L" is  $t_{SHORT}$  when the voltage V5 is increased after setting V1 = 3.4 V, V2 = 1.4 V, V5 = V6 = 0 V.

# 6. Load short-circuiting detection voltage 2 (Test circuit 2)

Load short-circuiting detection voltage 2 ( $V_{SHORT2}$ ) is defined as the voltage V2 whose delay time for changing  $V_{DO}$  from "H" to "L" is  $t_{SHORT}$  when the voltage V2 is increased after setting V1 = 3.4 V, V2 = V5 = V6 = 0 V.

# 7. Charge overcurrent detection voltage (Test circuit 2)

Charge overcurrent detection voltage (V<sub>CIOV</sub>) is defined as the voltage V5 whose delay time for changing V<sub>CO</sub> from "H" to "L" is charge overcurrent detection delay time (t<sub>CIOV</sub>) when the voltage V5 is decreased after setting V1 = 3.4 V, V2 = V5 = V6 = 0 V.

8. CTL pin voltage "H", CTL pin voltage "L" (Test circuit 2)

## 8.1 CTL pin control logic active "H"

The CTL pin voltage "H" (V<sub>CTLH</sub>) is defined as the voltage V6 at which V<sub>CO</sub> and V<sub>DO</sub> go from "H" to "L" when the voltage V6 is gradually increased after setting V1 = 3.4 V, V2 = V5 = V6 = 0 V.

After that, the CTL pin voltage "L" ( $V_{CTLL}$ ) is defined as the voltage V6 at which  $V_{CO}$  and  $V_{DO}$  go from "L" to "H" after V6 is gradually decreased.

#### 8.2 CTL pin control logic active "L"

 $V_{CTLL}$  is defined as the voltage difference between the voltage V6 and the voltage V1 (V1 – V6) at which  $V_{CO}$  and  $V_{DO}$  go from "H" to "L" when the voltage V6 is gradually increased after setting V1 = 3.4 V, V2 = V5 = V6 = 0 V. After that,  $V_{CTLH}$  is defined as V1 – V6 at which  $V_{CO}$  and  $V_{DO}$  go from "L" to "H" after V6 is gradually decreased.

# 9. Current consumption during operation (Test circuit 3)

The current consumption during operation ( $I_{OPE}$ ) is the current that flows through the VDD pin ( $I_{DD}$ ) under the set conditions of V1 = 3.4 V, V2 = V5 = V6 = 0 V. However, the current flowing through the CTL pin internal resistance is excluded.

# 10. Current consumption during power-down, current consumption during overdischarge (Test circuit 3)

#### 10.1 With power-down function

The current consumption during power-down ( $I_{PDN}$ ) is  $I_{DD}$  under the set conditions of V1 = V2 = 1.5 V, V5 = V6 = 0 V.

#### 10. 2 Without power-down function

The current consumption during overdischarge ( $I_{OPED}$ ) is  $I_{DD}$  under the set conditions of V1 = V2 = 1.5 V, V5 = V6 = 0 V.

### 11. Resistance between VDD pin and VM pin (Test circuit 3)

 $R_{VMD}$  is the resistance between VDD pin and VM pin under the set conditions of V1 = 1.8 V, V2 = V5 = V6 = 0 V.

# 12. Resistance between VM pin and VSS pin (Test circuit 3)

 $R_{VMS}$  is the resistance between VM pin and VSS pin when the voltage V5 is decreased to 0 V after setting V1 = 3.4 V, V2 = V5 = 1.0 V, V6 = 0 V.

# 13. CTL pin internal resistance (Test circuit 3)

#### 13.1 CTL pin control logic active "H" and CTL pin internal resistance connection "pull-up"

The CTL pin internal resistance ( $R_{CTL}$ ) is the resistance between CTL pin and VDD pin under the set conditions of V1 = 3.4 V, V2 = V5 = V6 = 0 V.

#### 13. 2 CTL pin control logic active "H" and CTL pin internal resistance connection "pull-down"

 $R_{CTL}$  is the resistance between CTL pin and VSS pin under the set conditions of V1 = V6 = 3.4 V, V2 = V5 = 0 V.

#### 13. 3 CTL pin control logic active "L" and CTL pin internal resistance connection "pull-up"

 $R_{CTL}$  is the resistance between CTL pin and VDD pin under the set conditions of V1 = V6 = 3.4 V, V2 = V5 = 0 V.

### 13. 4 CTL pin control logic active "L" and CTL pin internal resistance connection "pull-down"

 $R_{CTL}$  is the resistance between CTL pin and VSS pin under the set conditions of V1 = 3.4 V, V2 = V5 = V6 = 0 V.

#### 14. CO pin resistance "H" (Test circuit 4)

The CO pin resistance "H" ( $R_{COH}$ ) is the resistance between VDD pin and CO pin under the set conditions of V1 = 3.4 V, V2 = V5 = 0 V, V3 = 3.0 V.

#### 15. CO pin resistance "L" (Test circuit 4)

The CO pin resistance "L" ( $R_{COL}$ ) is the resistance between VM pin and CO pin under the set conditions of V1 = 4.7 V, V2 = V5 = 0 V, V3 = 0.4 V.

### 16. DO pin resistance "H" (Test circuit 4)

The DO pin resistance "H" ( $R_{DOH}$ ) is the resistance between VDD pin and DO pin under the set conditions of V1 = 3.4 V, V2 = V5 = 0 V, V4 = 3.0 V.

### 17. DO pin resistance "L" (Test circuit 4)

The DO pin resistance "L" ( $R_{DOL}$ ) is the resistance between VSS pin and DO pin under the set conditions of V1 = 1.8 V, V2 = V5 = 0 V, V4 = 0.4 V.

## Overcharge detection delay time (Test circuit 5)

After setting V1 = 3.4 V, V2 = V5 = V6 = 0 V, the voltage V1 is increased. The time interval from when the voltage V1 exceeds  $V_{CU}$  until  $V_{CO}$  goes to "L" is the overcharge detection delay time ( $t_{CU}$ ).

### 19. Overdischarge detection delay time (Test circuit 5)

After setting V1 = 3.4 V, V2 = V5 = V6 = 0 V, the voltage V1 is decreased. The time interval from when the voltage V1 falls below  $V_{DL}$  until  $V_{DO}$  goes to "L" is the overdischarge detection delay time ( $t_{DL}$ ).

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# 20. Discharge overcurrent detection delay time 1 (Test circuit 5)

After setting V1 = 3.4 V, V2 = 1.4 V, V5 = V6 = 0 V, the voltage V5 is increased. The time interval from when the voltage V5 exceeds  $V_{DIOV1}$  until  $V_{DO}$  goes to "L" is the discharge overcurrent detection delay time 1 ( $t_{DIOV1}$ ).

# 21. Discharge overcurrent detection delay time 2 (Test circuit 5)

After setting V1 = 3.4 V, V2 = 1.4 V, V5 = V6 = 0 V, the voltage V5 is increased. The time interval from when the voltage V5 exceeds  $V_{DIOV2}$  until  $V_{DO}$  goes to "L" is the discharge overcurrent detection delay time 2 ( $t_{DIOV2}$ ).

# 22. Load short-circuiting detection delay time (Test circuit 5)

After setting V1 = 3.4 V, V2 = 1.4 V, V5 = V6 = 0 V, the voltage V5 is increased. The time interval from when the voltage V5 exceeds V<sub>SHORT</sub> until V<sub>D0</sub> goes to "L" is the load short-circuiting detection delay time ( $t_{SHORT}$ ).

# 23. Charge overcurrent detection delay time (Test circuit 5)

After setting V1 = 3.4 V, V2 = V5 = V6 = 0 V, the voltage V5 is decreased. The time interval from when the voltage V5 falls below  $V_{CIOV}$  until  $V_{CO}$  goes to "L" is the charge overcurrent detection delay time ( $t_{CIOV}$ ).

# 24. Charge-discharge inhibition delay time (Test circuit 5)

### 24. 1 CTL pin control logic active "H"

After setting V1 = 3.4 V, V2 = V5 = V6 = 0 V, the voltage V6 is increased. The time interval from when the voltage V6 exceeds  $V_{CTLH}$  until  $V_{CO}$  and  $V_{DO}$  go to "L" is the charge-discharge inhibition delay time (t<sub>CTL</sub>).

## 24. 2 CTL pin control logic active "L"

After setting V1 = 3.4 V, V2 = V5 = V6 = 0 V, the voltage V6 is increased. The time interval from when the voltage V1 – V6 falls below  $V_{CTLL}$  until  $V_{CO}$  and  $V_{DO}$  go to "L" is  $t_{CTL}$ .

# 25. 0 V battery charge starting charger voltage (0 V battery charge enabled) (Test circuit 4)

The 0 V battery charge starting charger voltage ( $V_{0CHA}$ ) is defined as the absolute value of voltage V2 at which the current flowing through the CO pin (I<sub>CO</sub>) exceeds 1.0  $\mu$ A when the voltage V2 is gradually decreased after setting V1 = V5 = 0 V, V2 = V3 = -0.5 V.

# 26. 0 V battery charge inhibition battery voltage (0 V battery charge inhibited) (Test circuit 2)

The 0 V battery charge inhibition battery voltage ( $V_{0INH}$ ) is defined as the voltage V1 at which V<sub>CO</sub> goes to "L" (V<sub>CO</sub> = V<sub>VM</sub>) when the voltage V1 is gradually decreased after setting V1 = 1.8 V, V2 = -2.0 V, V5 = V6 = 0 V.

## BATTERY PROTECTION IC WITH CHARGE-DISCHARGE CONTROL FUNCTION FOR 1-CELL PACK S-82P1A Series Rev.1.0\_00

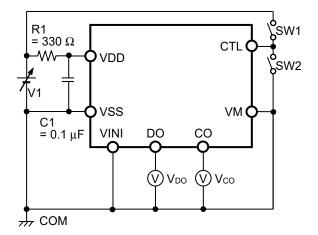
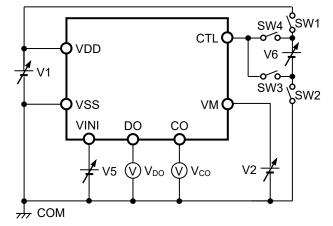


Figure 3 Test Circuit 1





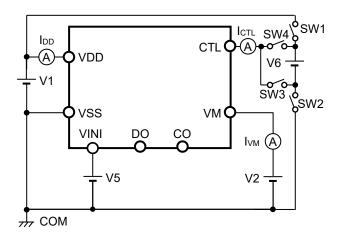


Figure 5 Test Circuit 3

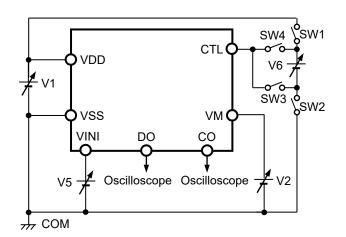


Figure 7 Test Circuit 5

SW1 CTL ( Ċ VDD SW2 V1 Ò VSS VM ( VINI DO СО r (A) IDO (A) ICO V5 V2 · V3 \/4 



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## Operation

Remark Refer to "
Battery Protection IC Connection Example".

### 1. Normal status

The S-82P1A Series monitors the voltage of the battery connected between VDD pin and VSS pin, the voltage between VINI pin and VSS pin, and the voltage between CTL pin and VSS pin to control charging and discharging.

### 1.1 CTL pin control logic active "H"

When the battery voltage is in the range from overdischarge detection voltage ( $V_{DL}$ ) to overcharge detection voltage ( $V_{CU}$ ), the VINI pin voltage is in the range from charge overcurrent detection voltage ( $V_{CIOV}$ ) to discharge overcurrent detection voltage 1 ( $V_{DIOV1}$ ), and the CTL pin voltage is equal to or lower than the CTL pin voltage "L" ( $V_{CTLL}$ ), the S-82P1A Series turns both the charge and discharge control FETs on. This status is called the normal status, and in this condition charging and discharging can be carried out freely.

The resistance between VDD pin and VM pin ( $R_{VMD}$ ), and the resistance between VM pin and VSS pin ( $R_{VMS}$ ) are not connected in the normal status.

### 1.2 CTL pin control logic active "L"

When the battery voltage is in the range from  $V_{DL}$  to  $V_{CU}$ , the VINI pin voltage is in the range from  $V_{CIOV}$  to  $V_{DIOV1}$ , and the CTL pin voltage is equal to or higher than the CTL pin voltage "H" ( $V_{CTLH}$ ), the S-82P1A Series turns both the charge and discharge control FETs on. This status is called the normal status, and in this condition charging and discharging can be carried out freely.

R<sub>VMD</sub> and R<sub>VMS</sub> are not connected in the normal status.

# Caution After the battery is connected, discharging may not be carried out. In this case, the S-82P1A Series returns to the normal status by connecting a charger.

### 2. Overcharge status

### 2. 1 $V_{CL} \neq V_{CU}$ (Product in which overcharge release voltage differs from overcharge detection voltage)

When the battery voltage becomes higher than  $V_{CU}$  during charging in the normal status and the condition continues for the overcharge detection delay time (t<sub>CU</sub>) or longer, the S-82P1A Series turns the charge control FET off to stop charging. This status is called the overcharge status.

The overcharge status is released in the following two cases.

- (1) In the case that the VM pin voltage is lower than 0.35 V typ., the S-82P1A Series releases the overcharge status when the battery voltage falls below overcharge release voltage (V<sub>CL</sub>).
- (2) In the case that the VM pin voltage is equal to or higher than 0.35 V typ., the S-82P1A Series releases the overcharge status when the battery voltage falls below  $V_{CU}$ .

When the discharge is started by connecting a load after the overcharge detection, the VM pin voltage rises by the V<sub>f</sub> voltage of the internal parasitic diode than the VSS pin voltage, because the discharge current flows through the parasitic diode in the charge control FET. If this VM pin voltage is equal to or higher than 0.35 V typ., the S-82P1A Series releases the overcharge status when the battery voltage is equal to or lower than V<sub>cu</sub>.

Caution If the battery is charged to a voltage higher than  $V_{CU}$  and the battery voltage does not fall below  $V_{CU}$ even when a heavy load is connected, discharge overcurrent detection and load short-circuiting detection do not function until the battery voltage falls below  $V_{CU}$ . Since an actual battery has an internal impedance of tens of m $\Omega$ , the battery voltage drops immediately after a heavy load that causes overcurrent is connected, and discharge overcurrent detection and load short-circuiting detection function.

### 2. 2 V<sub>CL</sub> = V<sub>CU</sub> (Product in which overcharge release voltage is the same as overcharge detection voltage)

When the battery voltage becomes higher than  $V_{CU}$  during charging in the normal status and the condition continues for  $t_{CU}$  or longer, the S-82P1A Series turns the charge control FET off to stop charging. This status is called the overcharge status.

In the case that the VM pin voltage is equal to or higher than 0.35 V typ. and the battery voltage falls below  $V_{CU}$ , the S-82P1A Series releases the overcharge status.

When the discharge is started by connecting a load after the overcharge detection, the VM pin voltage rises by the V<sub>f</sub> voltage of the internal parasitic diode than the VSS pin voltage, because the discharge current flows through the parasitic diode in the charge control FET. If this VM pin voltage is equal to or higher than 0.35 V typ., the S-82P1A Series releases the overcharge status when the battery voltage is equal to or lower than V<sub>CU</sub>.

- Caution 1. If the battery is charged to a voltage higher than V<sub>CU</sub> and the battery voltage does not fall below V<sub>CU</sub> even when a heavy load is connected, discharge overcurrent detection and load shortcircuiting detection do not function until the battery voltage falls below V<sub>CU</sub>. Since an actual battery has an internal impedance of tens of m $\Omega$ , the battery voltage drops immediately after a heavy load that causes overcurrent is connected, and discharge overcurrent detection and load short-circuiting detection function.
  - 2. When a charger is connected after overcharge detection, the overcharge status is not released even if the battery voltage is below V<sub>CL</sub>. The overcharge status is released when the discharge current flows and the VM pin voltage goes over 0.35 V typ. by removing the charger.

### 3. Overdischarge status

When the battery voltage falls below  $V_{DL}$  during discharging in the normal status and the condition continues for the overdischarge detection delay time ( $t_{DL}$ ) or longer, the S-82P1A Series turns the discharge control FET off to stop discharging. This status is called the overdischarge status.

Under the overdischarge status, VDD pin and VM pin are shorted by R<sub>VMD</sub> in the S-82P1A Series. The VM pin voltage is pulled up by R<sub>VMD</sub>.

When connecting a charger in the overdischarge status, the battery voltage reaches V<sub>DL</sub> or higher and the S-82P1A Series releases the overdischarge status if the VM pin voltage is below 0 V typ.

The battery voltage reaches the overdischarge release voltage ( $V_{DU}$ ) or higher and the S-82P1A Series releases the overdischarge status if the VM pin voltage is not below 0 V typ.

R<sub>VMS</sub> is not connected in the overdischarge status.

### 3.1 With power-down function

Under the overdischarge status, when the VM pin voltage is 0.7 V typ. or higher, the power-down function works and the current consumption is reduced to the current consumption during power-down ( $I_{PDN}$ ). By connecting a battery charger, the power-down function is released when the VM pin voltage is 0.7 V typ. or lower.

- When a battery is not connected to a charger and the VM pin voltage ≥ 0.7 V typ., the S-82P1A Seies maintains the overdischarge status even when the battery voltage reaches V<sub>DU</sub> or higher.
- When a battery is connected to a charger and 0.7 V typ. > the VM pin voltage > 0 V typ., the battery voltage reaches  $V_{DU}$  or higher and the S-82P1A Series releases the overdischarge status.
- When a battery is connected to a charger and 0 V typ. ≥ the VM pin voltage, the battery voltage reaches V<sub>DL</sub> or higher and the S-82P1A Series releases the overdischarge status.

#### 3. 2 Without power-down function

Under the overdischarge status, the power-down function does not work even when the VM pin voltage is 0.7 V typ. or higher.

- When a battery is not connected to a charger and the VM pin voltage  $\ge 0.7$  V typ., the battery voltage reaches V<sub>DU</sub> or higher and the S-82P1A Series releases the overdischarge status.
- When a battery is connected to a charger and 0.7 V typ. > the VM pin voltage > 0 V typ., the battery voltage reaches V<sub>DU</sub> or higher and the S-82P1A Series releases the overdischarge status.
- When a battery is connected to a charger and 0 V typ. ≥ the VM pin voltage, the battery voltage reaches V<sub>DL</sub> or higher and the S-82P1A Series releases the overdischarge status.

## 4. Discharge overcurrent status (discharge overcurrent 1, discharge overcurrent 2, load shortcircuiting, load short-circuiting 2)

### 4.1 Discharge overcurrent 1, discharge overcurrent 2, load short-circuiting

When a battery in the normal status is in the status where the VINI pin voltage is equal to or higher than  $V_{DIOV1}$  because the discharge current is equal to or higher than the specified value and the status continues for the discharge overcurrent detection delay time ( $t_{DIOV1}$ ) or longer, the discharge control FET is turned off and discharging is stopped. This status is called the discharge overcurrent status.

Under the discharge overcurrent status, VM pin and VSS pin are shorted by  $R_{VMS}$  in the S-82P1A Series. However, the VM pin voltage is the VDD pin voltage due to the load as long as the load is connected. When the load is disconnected, VM pin returns to the VSS pin voltage.

When the VM pin voltage returns to  $V_{\text{RIOV}}$  or lower, the S-82P1A Series releases the discharge overcurrent status.

R<sub>VMD</sub> is not connected in the discharge overcurrent status.

### 4. 2 Load short-circuiting 2

When a battery in the normal status is in the status where a load causing discharge overcurrent is connected, and the VM pin voltage is equal to or higher than  $V_{SHORT2}$  and the status continues for the load short-circuiting detection delay time ( $t_{SHORT}$ ) or longer, the discharge control FET is turned off and discharging is stopped. This status is called the discharge overcurrent status.

The S-82P1A Series releases the discharge overcurrent status in the same way as in "4. 1 Discharge overcurrent 1, discharge overcurrent 2, load short-circuiting".

#### 4. 3 Discharge overcurrent status reset function by CTL pin

#### 4. 3. 1 With discharge overcurrent status reset function by CTL pin

Under the discharge overcurrent status, when the CTL pin is active and the condition continues for the charge-discharge inhibition delay time ( $t_{CTL}$ ) or longer, the charge control FET and the discharge control FET are turned off, and charging and discharging are stopped. The S-82P1A Series then becomes the charge-discharge inhibition status.

The S-82P1A Series returns to the normal status if the CTL pin is made inactive and the chargedischarge inhibition status is released.

#### 4. 3. 2 Without discharge overcurrent status reset function by CTL pin

Under the discharge overcurrent status, even when the CTL pin is active and the condition continues for  $t_{CTL}$  or longer, the S-82P1A Series does not become the charge-discharge inhibition status and maintains the discharge overcurrent status.

The S-82P1A Series does not return to the normal status and maintains the discharge overcurrent status even if the CTL pin is made inactive.

### 5. Charge overcurrent status

When a battery in the normal status is in the status where the VINI pin voltage is equal to or lower than  $V_{CIOV}$  because the charge current is equal to or higher than the specified value and the status continues for the charge overcurrent detection delay time ( $t_{CIOV}$ ) or longer, the charge control FET is turned off and charging is stopped. This status is called the charge overcurrent status.

The S-82P1A Series releases the charge overcurrent status when the discharge current flows and the VM pin voltage is 0.35 V typ. or higher by removing the charger.

The charge overcurrent detection does not function in the overdischarge status.

## 6. Charge-discharge inhibition status

### 6.1 CTL pin control logic active "H"

When the CTL pin voltage is equal to or higher than CTL pin voltage "H" ( $V_{CTLH}$ ) and the status continues for the charge-discharge inhibition delay time ( $t_{CTL}$ ) or longer, the charge control FET and the discharge control FET are turned off, and charging and discharging are stopped. This status is called the charge-discharge inhibition status.

The S-82P1A Series releases charge-discharge inhibition status when the CTL pin voltage is equal to or lower than CTL pin voltage "L" (V<sub>CTLL</sub>).

### 6. 2 CTL pin control logic active "L"

When the CTL pin voltage is equal to or lower than  $V_{CTLL}$  and the status continues for  $t_{CTL}$  or longer, the charge control FET and the discharge control FET are turned off, and charging and discharging are stopped. This status is called the charge-discharge inhibition status.

The S-82P1A Series releases charge-discharge inhibition status when the CTL pin voltage is equal to or higher than  $V_{CTLH}$ .

#### 6.3 CTL pin internal resistance connection

### 6. 3. 1 CTL pin internal resistance connection "pull-up"

The CTL pin is shorted to the VDD pin by the CTL pin internal resistance (RCTL).

### 6. 3. 2 CTL pin internal resistance connection "pull-down"

The CTL pin is shorted to the VSS pin by R<sub>CTL</sub>.

When the S-82P1A Series becomes overdischarge status,  $R_{CTL}$  is disconnected, and the input current and the output current to the CTL pin are cut off.

The charge-discharge control by the CTL pin does not function in the overdischarge status.

## 7. 0 V battery charge enabled

This function is used to recharge a connected battery whose voltage is 0 V due to self-discharge. When the 0 V battery charge starting charger voltage ( $V_{0CHA}$ ) or a higher voltage is applied between the EB+ and EB- pins by connecting a charger, the charge control FET gate is fixed to the VDD pin voltage.

When the voltage between the gate and source of the charge control FET becomes equal to or higher than the threshold voltage due to the charger voltage, the charge control FET is turned on to start charging. At this time, the discharge control FET is off and the charging current flows through the internal parasitic diode in the discharge control FET. When the battery voltage becomes equal to or higher than  $V_{DL}$ , the S-82P1A Series returns to the normal status.

- Caution 1. Some battery providers do not recommend charging for a completely self-discharged lithium-ion rechargeable battery. It depends on the characteristics of the lithium-ion rechargeable battery to be used; therefore, please ask the battery provider to determine whether to enable or inhibit the 0 V battery charge.
  - 2. The 0 V battery charge has higher priority than the charge overcurrent detection function. Consequently, a product in which use of the 0 V battery charge is enabled charges a battery forcibly and the charge overcurrent cannot be detected when the battery voltage is lower than V<sub>DL</sub>.

### 8. 0 V battery charge inhibited

This function inhibits charging when a battery that is internally short-circuited (0 V battery) is connected. When the battery voltage is the 0 V battery charge inhibition battery voltage ( $V_{0INH}$ ) or lower, the charge control FET gate is fixed to the EB- pin voltage to inhibit charging. When the battery voltage is  $V_{0INH}$  or higher, charging can be performed.

Caution Some battery providers do not recommend charging for a completely self-discharged lithium-ion rechargeable battery. It depends on the characteristics of the lithium-ion rechargeable battery to be used; therefore, please ask the battery provider to determine whether to enable or inhibit the 0 V battery charge.

### 9. Delay circuit

The detection delay times are determined by dividing a clock of approximately 4 kHz by the counter.

**Remark** t<sub>DIOV1</sub>, t<sub>DIOV2</sub> and t<sub>SHORT</sub> start when V<sub>DIOV1</sub> is detected. When V<sub>DIOV2</sub> or V<sub>SHORT</sub> is detected over t<sub>DIOV2</sub> or t<sub>SHORT</sub> after the detection of V<sub>DIOV1</sub>, the S-82P1A Series turns the discharge control FET off within t<sub>DIOV2</sub> or t<sub>SHORT</sub> of each detection.

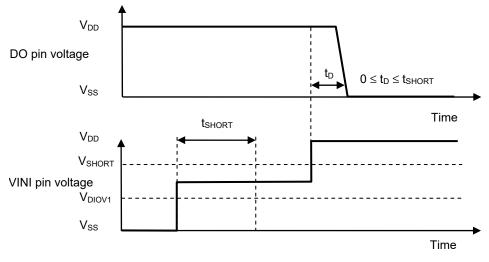
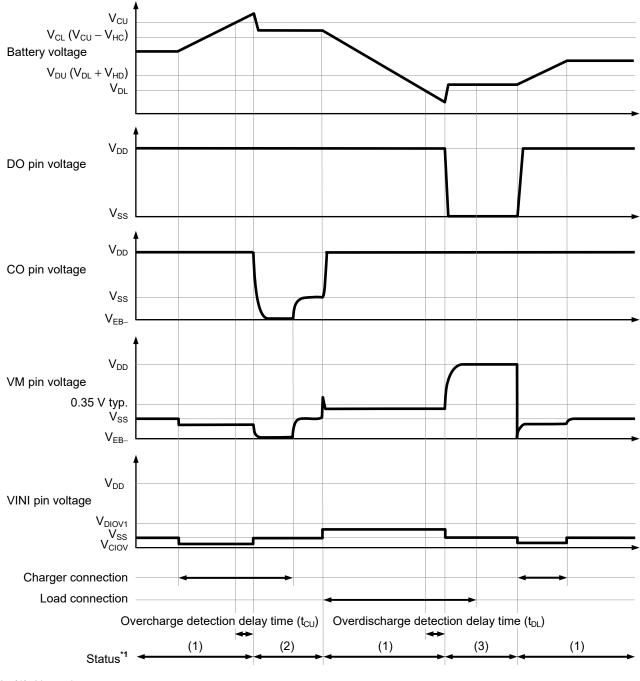


Figure 8

## Timing Charts

## 1. Overcharge detection, overdischarge detection



\*1. (1): Normal status

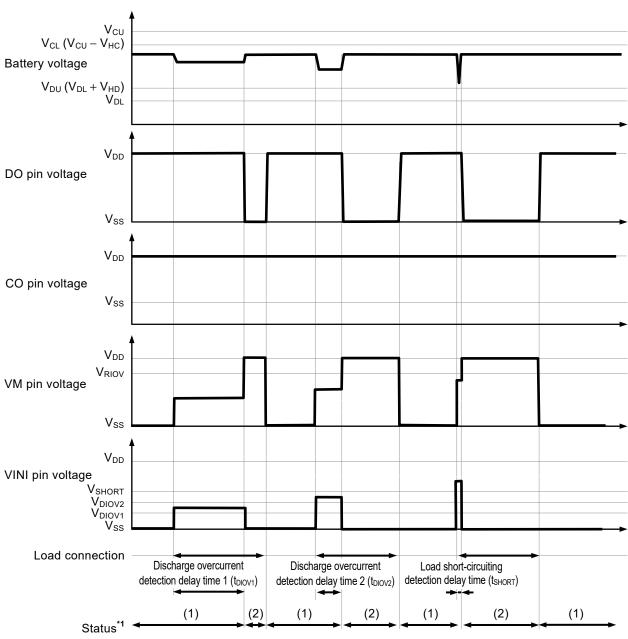
(2): Overcharge status

(3): Overdischarge status

Remark The charger is assumed to charge with a constant current.

Figure 9

## BATTERY PROTECTION IC WITH CHARGE-DISCHARGE CONTROL FUNCTION FOR 1-CELL PACK Rev.1.0\_00 S-82P1A Series



## 2. Discharge overcurrent detection

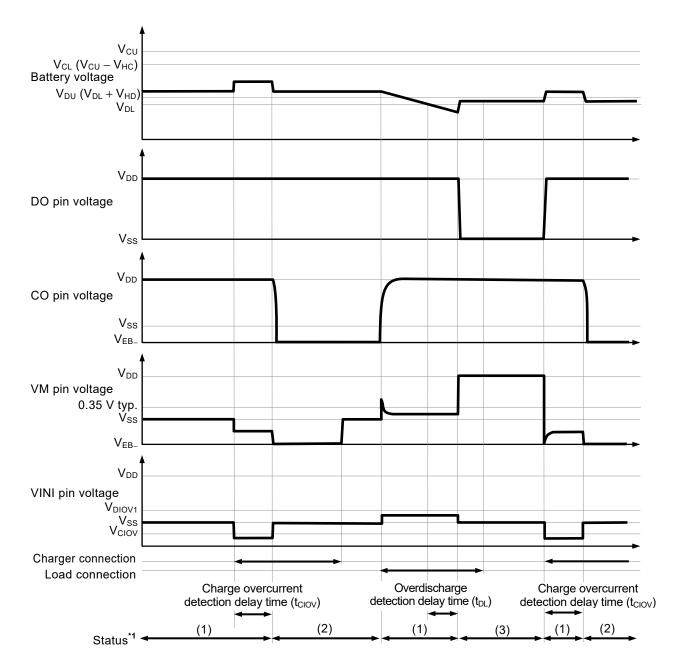
\*1. (1): Normal status

(2): Discharge overcurrent status

Remark The charger is assumed to charge with a constant current.

Figure 10

## BATTERY PROTECTION IC WITH CHARGE-DISCHARGE CONTROL FUNCTION FOR 1-CELL PACK S-82P1A Series Rev.1.0\_00



## 3. Charge overcurrent detection

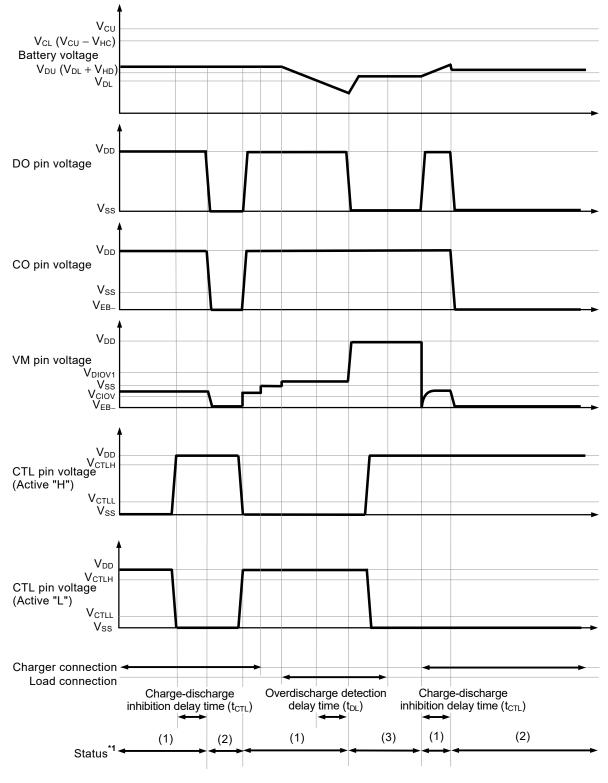
\*1. (1): Normal status

(2): Charge overcurrent status

(3): Overdischarge status

Remark The charger is assumed to charge with a constant current.

Figure 11



## 4. Charge-discharge inhibition operation

\*1. (1): Normal status

(2): Charge-discharge inhibition status

(3): Overdischarge status

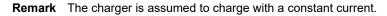


Figure 12

## Battery Protection IC Connection Example

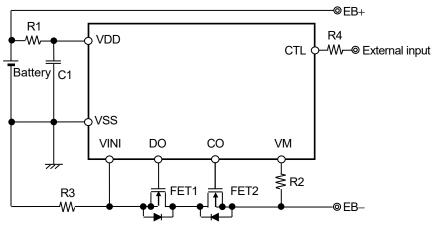


Figure 13

Table 13 Constants for External Components	5
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Symbol	Part	Purpose	Min.	Тур.	Max.	Remark
FET1	N-channel MOS FET	Discharge control	-	_	_	Threshold voltage $\leq$ Overdischarge detection voltage <sup>*1</sup>
FET2	N-channel MOS FET	Charge control	_	-	-	Threshold voltage $\leq$ Overdischarge detection voltage <sup>*1</sup>
R1	Resistor	ESD protection, For power fluctuation	270 Ω	330 Ω	1.2 kΩ*²	_
C1	Capacitor	For power fluctuation	0.068 μF	0.1 μF	2.2 μF	-
R2	Resistor	ESD protection, Protection for reverse connection of a charger	270 Ω	470 Ω	1.5 kΩ	_
R3	Resistor	Overcurrent detection	_	$0.75~m\Omega$	_	_
R4	Resistor	CTL pin input protection	_	1 kΩ	_	_

\*1. If a FET with a threshold voltage equal to or higher than the overdischarge detection voltage is used, discharging may be stopped before overdischarge is detected.

\*2. Accuracy of overcharge detection voltage is guaranteed by R1 = 330  $\Omega$ . Connecting resistors with other values will worsen the accuracy.

Caution 1. The constants may be changed without notice.

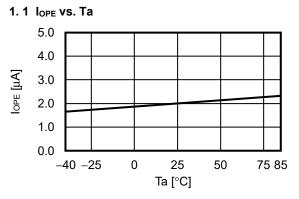
2. It has not been confirmed whether the operation is normal or not in circuits other than the connection example. In addition, the connection example and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.

## Precautions

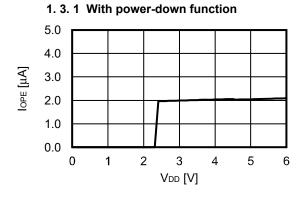
- The application conditions for the input voltage, output voltage, and load current should not exceed the power dissipation.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- ABLIC Inc. claims no responsibility for any and all disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

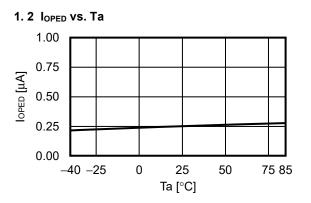
# ■ Characteristics (Typical Data)

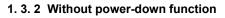
## 1. Current consumption

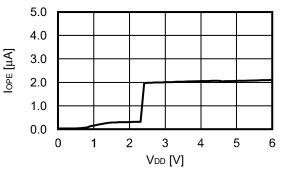


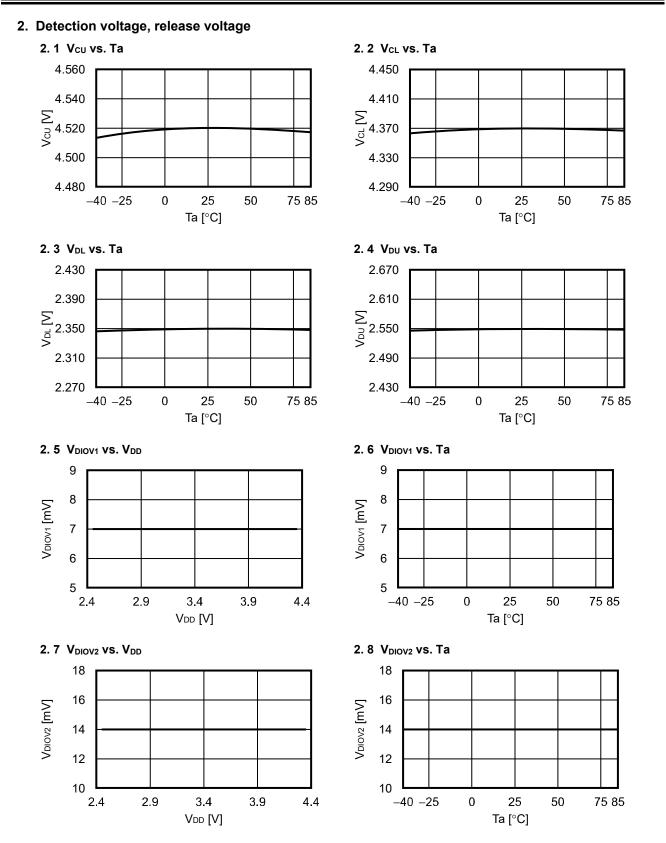
## 1.3 $I_{OPE}$ vs. $V_{DD}$





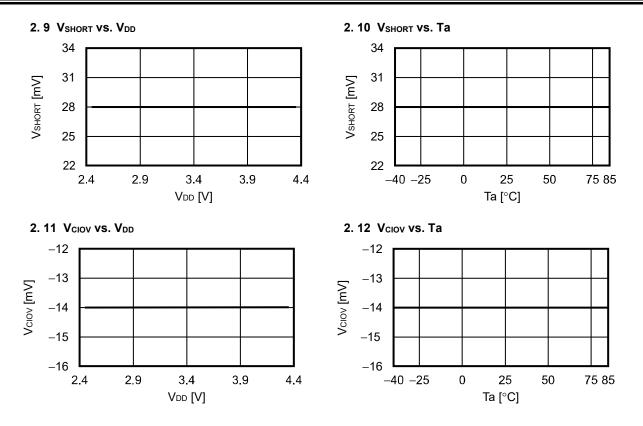






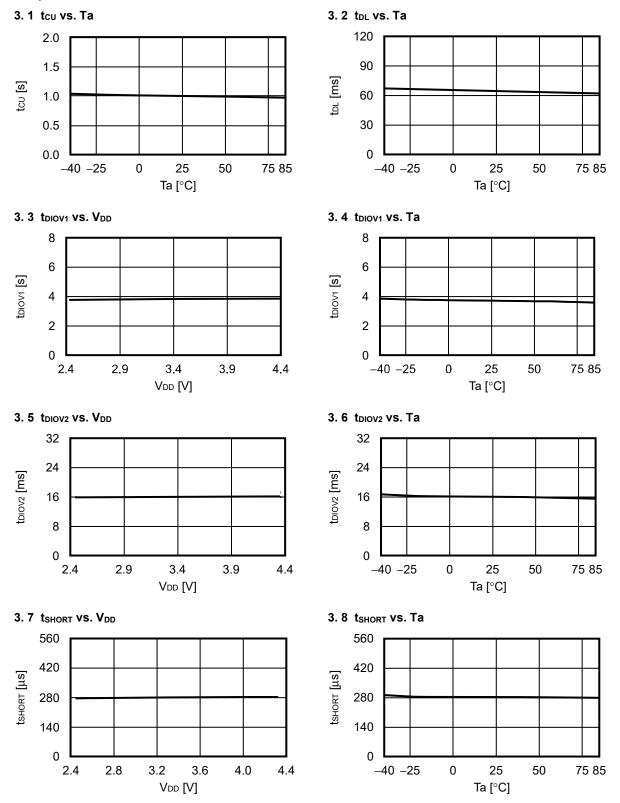
ABLIC Inc.

# BATTERY PROTECTION IC WITH CHARGE-DISCHARGE CONTROL FUNCTION FOR 1-CELL PACK S-82P1A Series Rev.1.0\_00

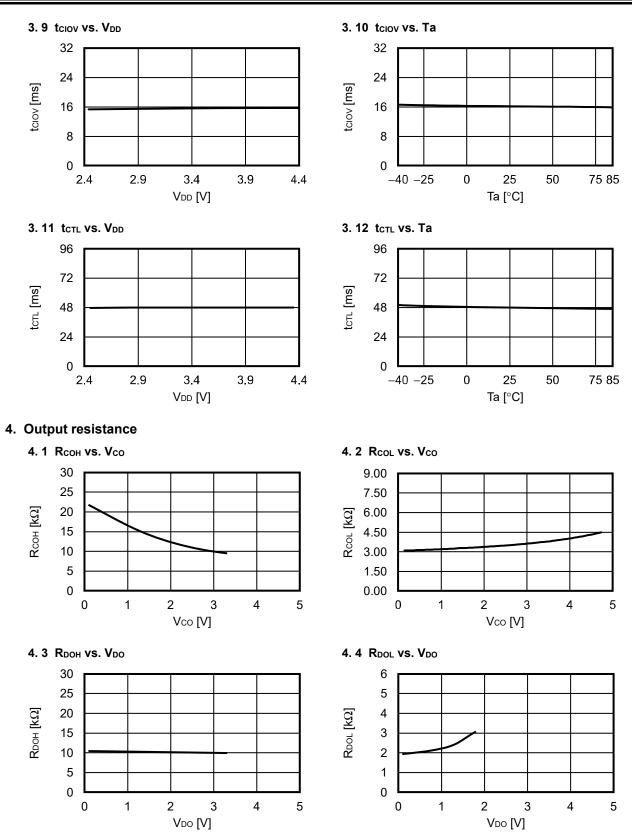


## BATTERY PROTECTION IC WITH CHARGE-DISCHARGE CONTROL FUNCTION FOR 1-CELL PACK Rev.1.0\_00 S-82P1A Series

## 3. Delay time

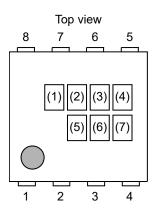


## BATTERY PROTECTION IC WITH CHARGE-DISCHARGE CONTROL FUNCTION FOR 1-CELL PACK S-82P1A Series Rev.1.0\_00



## Marking Specifications

## 1. HSNT-8(1616)



(1): (2) to (4): (5) to (7): Blank

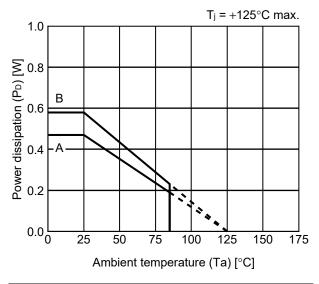
Product code (refer to **Product name vs. Product code**) Lot number

## Product name vs. Product code

Draduat Nama	Product Code				
Product Name	(2)	(3)	(4)		
S-82P1AAA-A8T2U	8	1	А		

# Power Dissipation

## HSNT-8(1616)

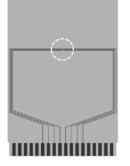


Board	Power Dissipation (P <sub>D</sub> )
А	0.47 W
В	0.58 W
С	_
D	_
E	_

# HSNT-8(1616) Test Board

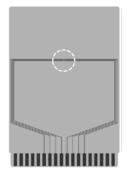
## 🔵 IC Mount Area

## (1) Board A



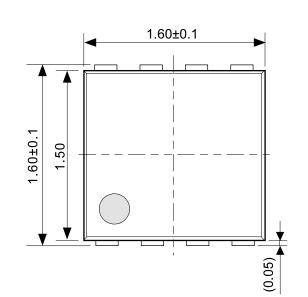
Item		Specification		
Size [mm]		114.3 x 76.2 x t1.6		
Material		FR-4		
Number of copper foil layer		2		
	1	Land pattern and wiring for testing: t0.070		
Coppor foil lover [mm]	2	-		
Copper foil layer [mm]	3	-		
	4	74.2 x 74.2 x t0.070		
Thermal via		-		

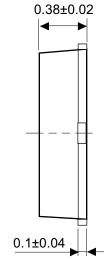
## (2) Board B

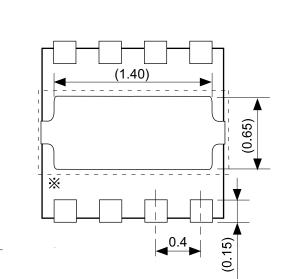


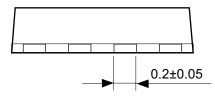
Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		-

No. HSNT8-B-Board-SD-1.0





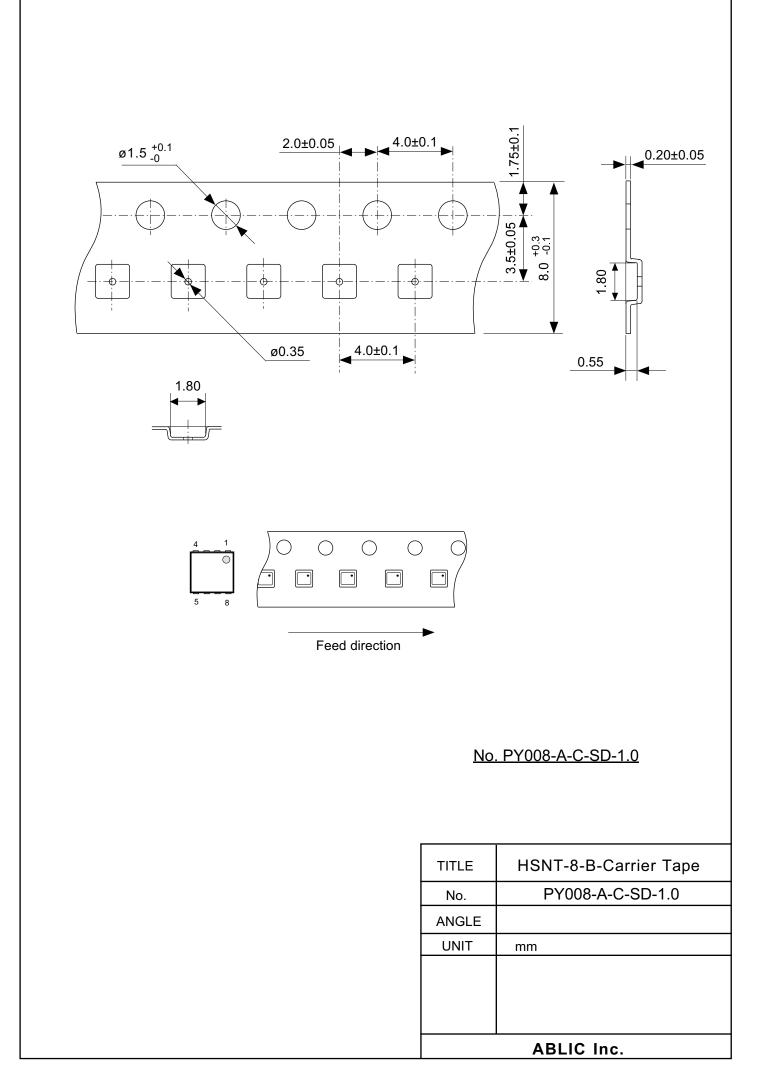


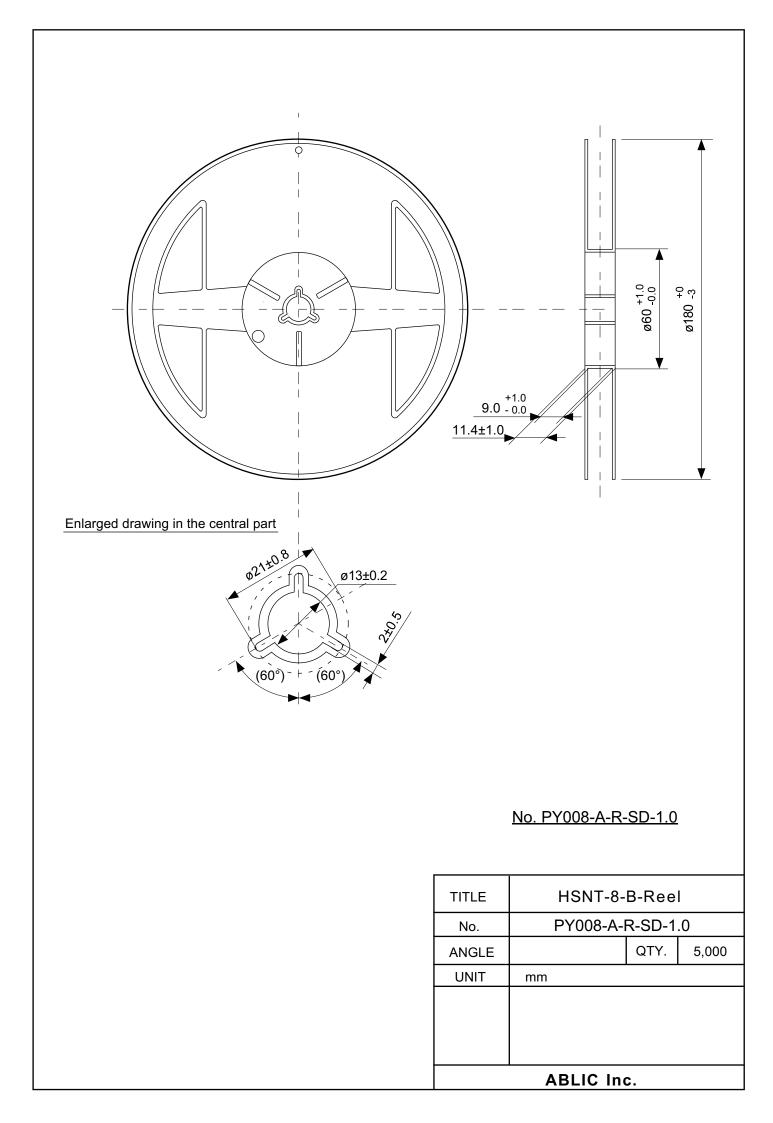


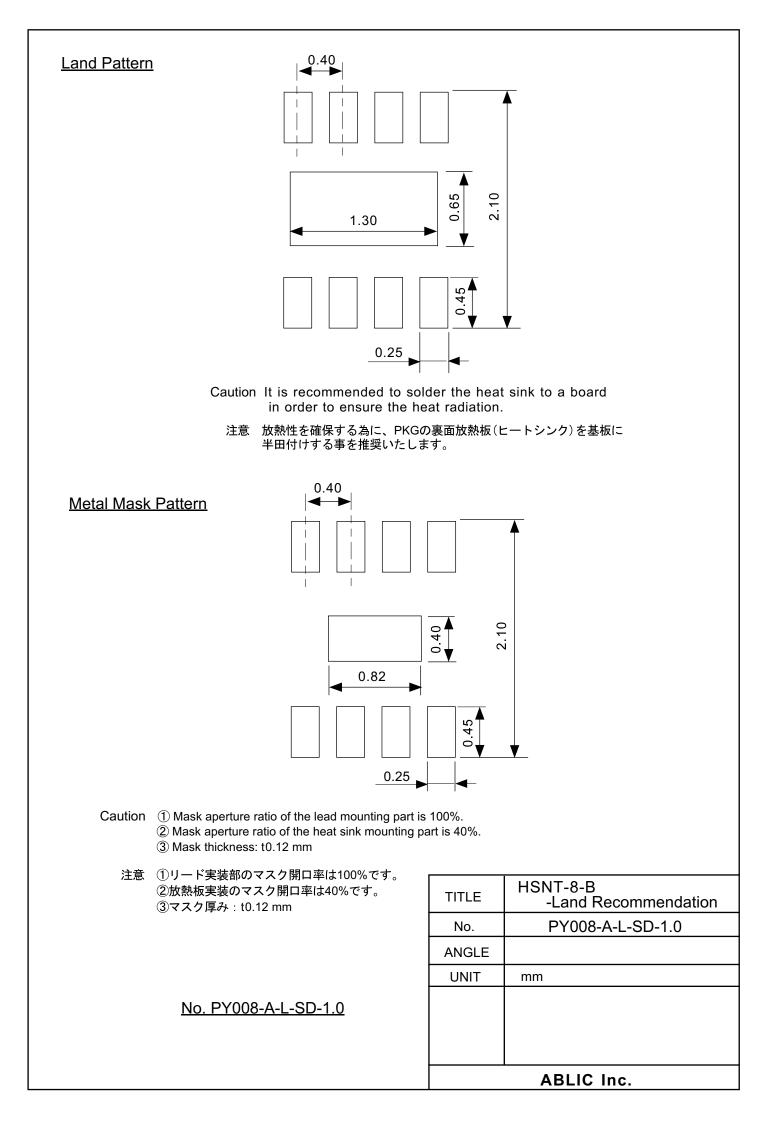
The heat sink of back side has different electric potential depending on the product.
 Confirm specifications of each product.
 Do not use it as the function of electrode.

No. PY008-A-P-SD-1.0

TITLE	HSNT-8-B-PKG Dimensions		
No.	PY008-A-P-SD-1.0		
ANGLE	$\oplus$		
UNIT	mm		
	ABLIC Inc.		







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